

Silicon Power Schottky Diode

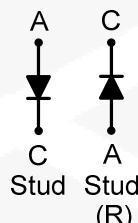
$V_{RRM} = 20 \text{ V - } 40 \text{ V}$

$I_F = 15 \text{ A}$

Features

- High Surge Capability
- Types from 20 V to 40 V V_{RRM}
- Not ESD Sensitive

DO-4 Package



Note:

1. Standard polarity: Stud is cathode.
2. Reverse polarity (R): Stud is anode.
3. Stud is base.

Maximum ratings, at $T_j = 25^\circ\text{C}$, unless otherwise specified ("R" devices have leads reversed)

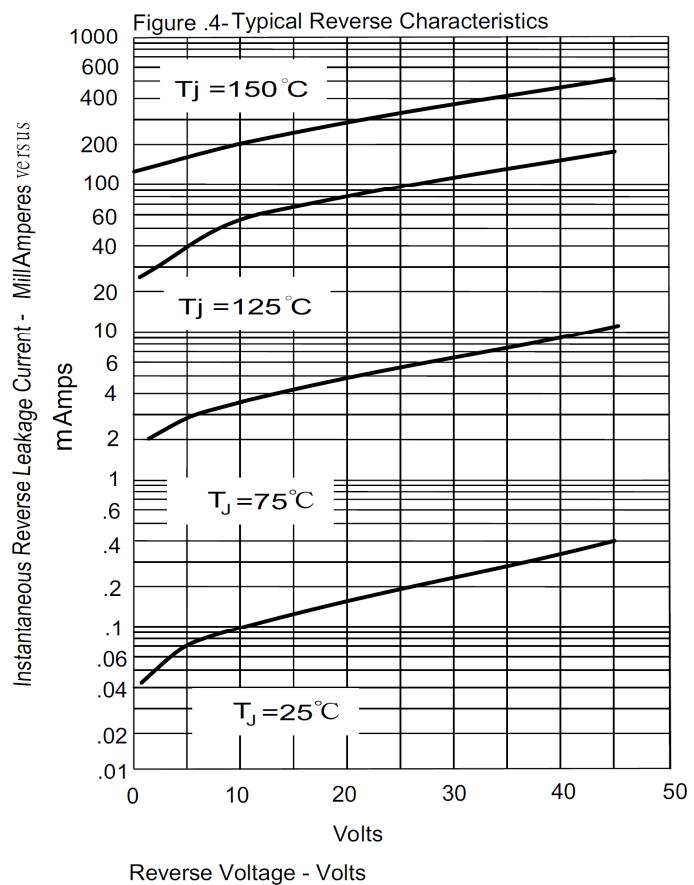
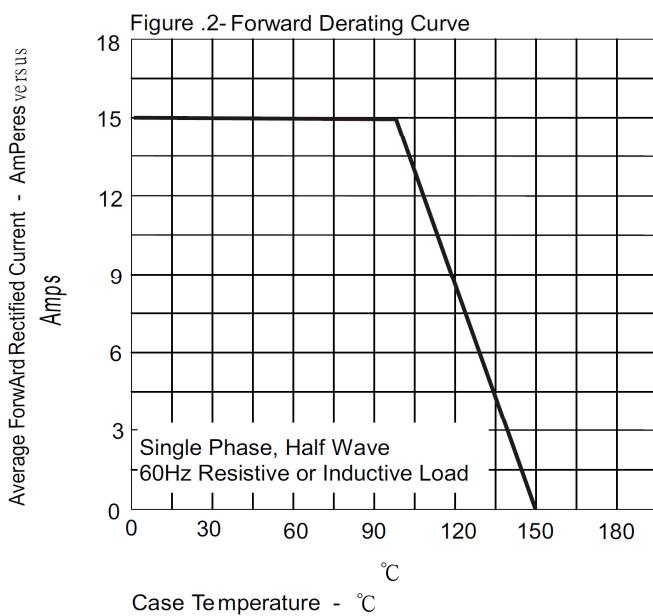
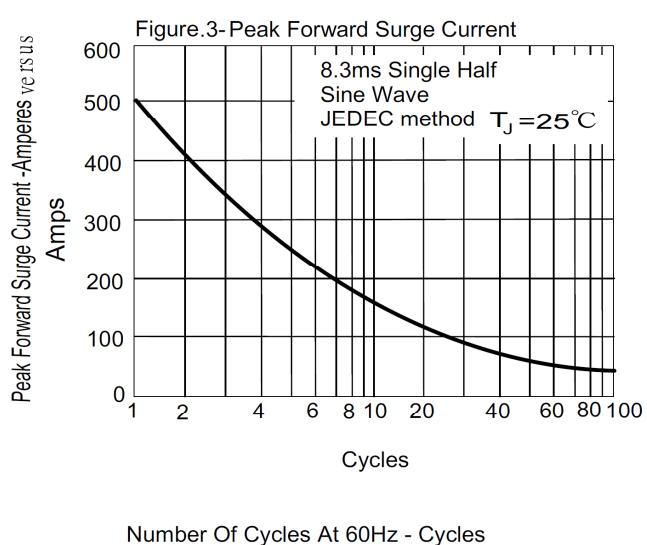
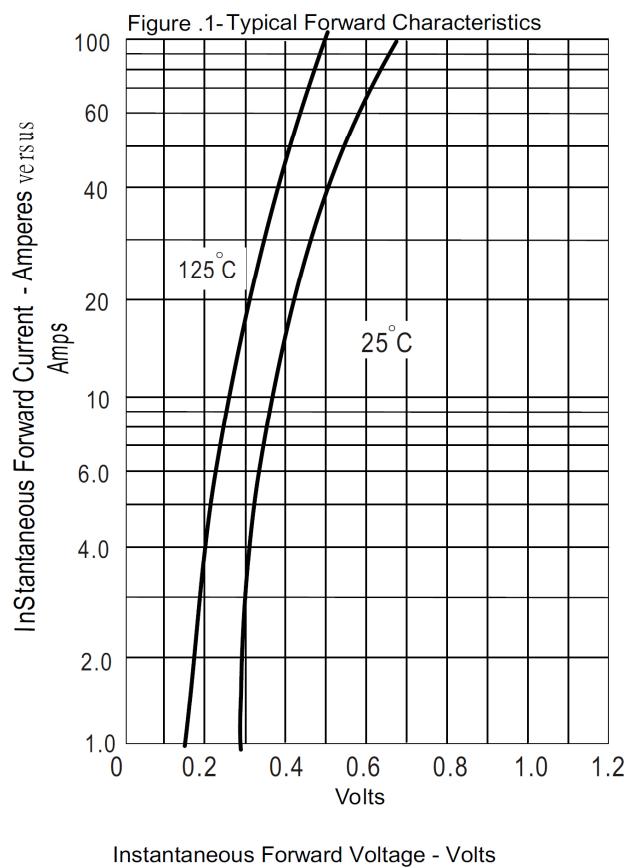
Parameter	Symbol	Conditions	1N5826 (R)	1N5827 (R)	1N5828 (R)	Unit
Repetitive peak reverse voltage	V_{RRM}		20	30	40	V
RMS reverse voltage	V_{RMS}		14	21	28	V
DC blocking voltage	V_{DC}		20	30	40	V
Continuous forward current	I_F	$T_C \leq 100^\circ\text{C}$	15	15	15	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25^\circ\text{C}, t_p = 8.3 \text{ ms}$	500	500	500	A
Operating temperature	T_j		-55 to 150	-55 to 150	-55 to 150	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to 150	-55 to 150	-55 to 150	$^\circ\text{C}$

Electrical characteristics, at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	1N5826 (R)	1N5827 (R)	1N5828 (R)	Unit
Diode forward voltage	V_F	$I_F = 15 \text{ A}, T_j = 25^\circ\text{C}$	0.44	0.47	0.5	V
Reverse current	I_R	$V_R = 20 \text{ V}, T_j = 25^\circ\text{C}$ $V_R = 20 \text{ V}, T_j = 125^\circ\text{C}$	10 250	10 250	10 250	mA

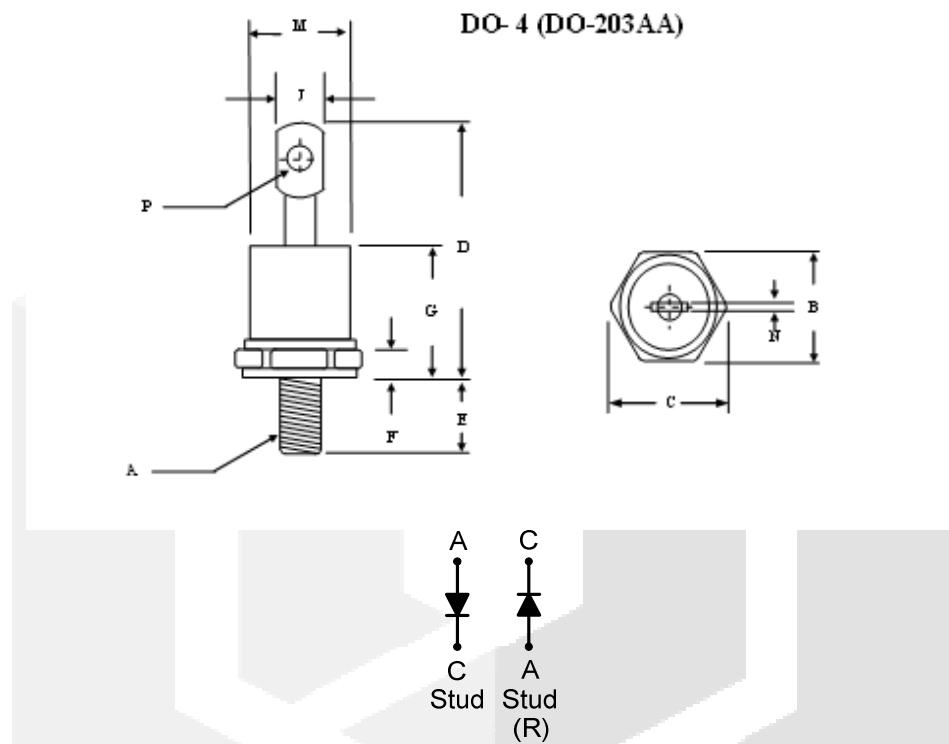
Thermal characteristics

Thermal resistance, junction - case	R_{thJC}	1.8	1.8	1.8	$^\circ\text{C/W}$
-------------------------------------	------------	-----	-----	-----	--------------------



Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



	Inches		Millimeters	
	Min	Max	Min	Max
10-32 UNF				
B	0.424	0.437	10.77	11.10
C	---	0.505	---	12.82
D	----	0.800	----	20.30
E	0.453	0.492	11.50	12.50
F	0.114	0.140	2.90	3.50
G	----	0.405	----	10.29
J	----	0.216	----	5.50
M	----	Φ0.302	----	Φ7.68
N	0.031	0.045	0.80	1.15
P	0.070	0.79	1.80	2.00

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by GeneSiC Semiconductor manufacturer:

Other Similar products are found below :

[CUS06\(TE85L,Q,M\)](#) [MA4E2039](#) [D1FH3-5063](#) [MBR0530L-TP](#) [MBR10100CT-BP](#) [MBR30H100MFST1G](#) [MMBD301M3T5G](#) [PMAD1103-LF](#) [PMAD1108-LF](#) [RB160M-50TR](#) [RB520S-30](#) [RB551V-30](#) [DD350N18K](#) [DZ435N40K](#) [DZ600N16K](#) [BAS16E6433HTMA1](#) [BAS 3010S-02LRH E6327](#) [BAT 54-02LRH E6327](#) [IDL02G65C5XUMA1](#) [NSR05F40QNXT5G](#) [JANS1N6640](#) [SB07-03C-TB-H](#) [SB1003M3-TL-W](#) [SBAT54CWT1G](#) [SK32A-LTP](#) [SK33A-TP](#) [SK34A-TP](#) [SK34B-TP](#) [SMD1200PL-TP](#) [ACDBN160-HF](#) [SS3003CH-TL-E](#) [STPS30S45CW](#) [PDS3100Q-7](#) [GA01SHT18](#) [CRS10I30A\(TE85L,QM\)](#) [MA4E2501L-1290](#) [MBR1240MFST1G](#) [MBRB30H30CT-1G](#) [BAS28E6433HTMA1](#) [BAS 70-02L E6327](#) [HSB123JTR-E](#) [JANTX1N5712-1](#) [VS-STPS40L45CW-N3](#) [DD350N12K](#) [SB007-03C-TB-E](#) [SK110-LTP](#) [SK154-TP](#) [SK32A-TP](#) [SK33B-TP](#) [SK35A-TP](#)